Impact of external screening on the valence and core-level photoelectron spectra of one-layer WS_2

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In an effectively-screened environment, transition metal dichalcogenides (TMDs) rearrange their charge carriers to screen the added charges, and reduce the electronic band gap. Consequently, when interfaced with dissimilar materials, a sheet of TMD would change its band gap adapted to its local external screening environment. Similarly, a well-screened environment stabilizes photo-holes or core-holes created in the photoemission process and, in turn, boosts the kinetic energy of photoelectrons resulting in the apparent smaller binding energy. Complication arises when determining the electronic band alignment of TMDs using photoelectron spectroscopy since the screening influences the material property of interest as well as its assessment approach concurrently. Using a sample that contains areas of suspended and gold-supported one-layer WS_2, we show how the electronic states of WS_2 under the contrasting effective or ineffective external screening environment align at the built-in junction. The photoelectron spectra point to the breakdown of rigid shifts between the valence states and core-levels with the core-levels shifting more than twice as much as the valence states. Additionally, effectively-screened WS_2 displays a valence state with a substantially larger photoemission linewidth than ineffectively-screened suspended WS_2. Altogether, our result provides key insights into how the local variation of the external screening environment creates essentially a heterojunction within a layer of WS_2, and whether commonly accepted photoelectron spectroscopy practices hold when examining the electronic structures of one-layer TMDs.

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